

TIP30
TIP30A
TIP30B
TIP30C

SILICON
PNP POWER TRANSISTORS



www.centrasemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR TIP30 series devices are silicon PNP epitaxial-base power transistors designed for power amplifier and high speed switching applications.

MARKING: FULL PART NUMBER



TO-220 CASE

MAXIMUM RATINGS: ($T_C=25^\circ\text{C}$ unless otherwise noted)

	SYMBOL	TIP30	TIP30A	TIP30B	TIP30C	UNITS
Collector-Base Voltage	V_{CBO}	40	60	80	100	V
Collector-Emitter Voltage	V_{CEO}	40	60	80	100	V
Emitter-Base Voltage	V_{EBO}			5.0		V
Continuous Collector Current	I_C			1.0		A
Peak Collector Current	I_{CM}			3.0		A
Continuous Base Current	I_B			0.4		A
Power Dissipation	P_D			30		W
Power Dissipation ($T_A=25^\circ\text{C}$)	P_D			2.0		W
Operating and Storage Junction Temperature	T_J, T_{stg}			-65 to +150		$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS: ($T_C=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
I_{CEO}	$V_{CE}=30\text{V}$ (TIP30, TIP30A)			0.3	mA
I_{CEO}	$V_{CE}=60\text{V}$ (TIP30B, TIP30C)			0.3	mA
I_{CES}	$V_{CE}=\text{Rated } V_{CEO}$			0.2	mA
I_{EBO}	$V_{EB}=5.0\text{V}$			1.0	mA
BV_{CEO}	$I_C=30\text{mA}$ (TIP30)	40			V
BV_{CEO}	$I_C=30\text{mA}$ (TIP30A)	60			V
BV_{CEO}	$I_C=30\text{mA}$ (TIP30B)	80			V
BV_{CEO}	$I_C=30\text{mA}$ (TIP30C)	100			V
$V_{CE(SAT)}$	$I_C=1.0\text{A}, I_B=125\text{mA}$			0.7	V
$V_{BE(ON)}$	$V_{CE}=4.0\text{V}, I_C=1.0\text{A}$			1.3	V
h_{FE}	$V_{CE}=4.0\text{V}, I_C=0.2\text{A}$	40			
h_{FE}	$V_{CE}=4.0\text{V}, I_C=1.0\text{A}$	15		75	
h_{fe}	$V_{CE}=10\text{V}, I_C=0.2\text{A}, f=1.0\text{kHz}$	20			
f_T	$V_{CE}=10\text{V}, I_C=0.2\text{A}, f=1.0\text{MHz}$	3.0			MHz
t_{on}	$I_C=1.0\text{A}, I_{B1}=I_{B2}=0.1\text{A}, R_L=30\Omega$		0.3		μs
t_{off}	$I_C=1.0\text{A}, I_{B1}=I_{B2}=0.1\text{A}, R_L=30\Omega$		1.0		μs

R1 (12-March 2014)

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TO-220 CASE - MECHANICAL OUTLINE



R2

LEAD CODE:

- 1) Base
- 2) Collector
- 3) Emitter
- Tab) Collector

MARKING:
FULL PART NUMBER

SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.170	0.190	4.31	4.82
B	0.045	0.055	1.15	1.39
C	0.013	0.026	0.33	0.65
D	0.083	0.107	2.10	2.72
E	0.394	0.417	10.01	10.60
F (DIA)	0.140	0.157	3.55	4.00
G	0.100	0.118	2.54	3.00
H	0.230	0.270	5.85	6.85
I	0.560	0.625	14.23	15.87
J	-	0.250	-	6.35
K	0.025	0.038	0.64	0.96
L	0.500	0.579	12.70	14.70
M	0.090	0.110	2.29	2.79

TO-220 (REV: R2)

R1 (12-March 2014)

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options
- Custom bar coding for shipments
- Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities
- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

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